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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



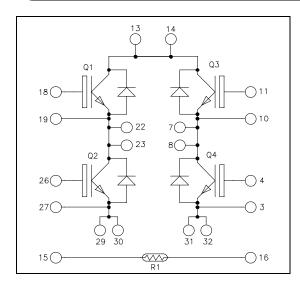


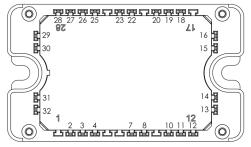


Full bridge High speed Trench + Field Stop IGBT4 Power Module

$$V_{CES} = 650V$$

 $I_{C} = 30A$ @ $Tc = 50$ °C





All multiple inputs and outputs must be shorted together; Example: 13/14; 29/30; 22/23...

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
- Very low stray inductance
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals for both power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS compliant

All ratings (a) $T_i = 25$ °C unless otherwise specified

Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		650	V
T	Continuous Collector Current	$\Gamma_{\rm C} = 25^{\circ}{\rm C}$	40	
I_{C}	Continuous Collector Current $T_{C} = 50$		30	Α
I_{CM}	Pulsed Collector Current	$\Gamma_{\rm C} = 25^{\circ}{\rm C}$	80	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Power Dissipation		95	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$				50	μΑ
V	Collector Emitter Saturation Voltage	$ \begin{array}{c c} V_{GE} = 15V & T_j = 25^{\circ}C \\ I_C = 30A & T_j = 150^{\circ}C \\ \end{array} $	$T_j = 25^{\circ}C$	1.5	1.95	2.3	V
$V_{CE(sat)}$			$T_j = 150$ °C		2.3		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 0.43 \text{ mA}$		4.2	5.1	5.6	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				300	nA

Dynamic Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	5	Min	Typ	Max	Unit
C _{ies}	Input Capacitance	$V_{GE} = 0V$	$V_{GE} = 0V$ $V_{CE} = 25V$		1900		
C _{oes}	Output Capacitance				62		pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz			55		
Q_{G}	Gate charge	$V_{GE} = 15V, I_{C} = V_{CE} = 480V$	$V_{GE} = 15V, I_C = 30A$ $V_{CE} = 480V$		170		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switc	hing (25°C)		19		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 400V$			33		ns
$T_{d(off)}$	Turn-off Delay Time	$I_C = 30A$			197		
$T_{\rm f}$	Fall Time	$R_G = 12\Omega$			21		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C)			19		ns
$T_{\rm r}$	Rise Time		$V_{GE} = \pm 15V$ $V_{Bus} = 400V$ $I_{C} = 30A$ $R_{G} = 12\Omega$		29		
T _{d(off)}	Turn-off Delay Time				227		
T_{f}	Fall Time	-			22		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 400V$	$T_j = 150$ °C		0.74		mJ
E_{off}	Turn off Energy	$I_{C} = 30A$ $R_{G} = 12\Omega$	$T_j = 150$ °C		0.6		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V ; V_{Bus} = 400V t_p \le 5\mu s ; T_j = 150^{\circ}C$			190		A
R_{thJC}	Junction to Case Thermal Resistance					1.59	°C/W

Diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Peak Repetitive Reverse Voltage					650	V
I_{RM}	Reverse Leakage Current	$V_R = 650V$				50	μA
I_F	DC Forward Current		Tc = 25°C		30		Α
$V_{\rm F}$	Diode Forward Voltage	$I_F = 30A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$ $T_i = 150^{\circ}C$		1.6 1.5	2	V
t _{rr}	Reverse Recovery Time	$I_{F} = 30A \\ V_{R} = 300V \\ di/dt = 1800A/\mu s$	$T_j = 25^{\circ}C$ $T_i = 150^{\circ}C$		100 150		ns
Q _{rr}	Reverse Recovery Charge		$T_{j} = 25^{\circ}C$ $T_{i} = 150^{\circ}C$		1.5		μС
E _{rr}	Reverse Recovery Energy		$T_j = 25^{\circ}C$ $T_j = 150^{\circ}C$		0.34 0.75		mJ
R_{thJC}	Junction to Case Thermal Resistance	•	•			2.45	°C/W



$Temperature \ sensor \ NTC \ (\text{see application note APT0406 on www.microsemi.com}). \\$

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C	ce @ 25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

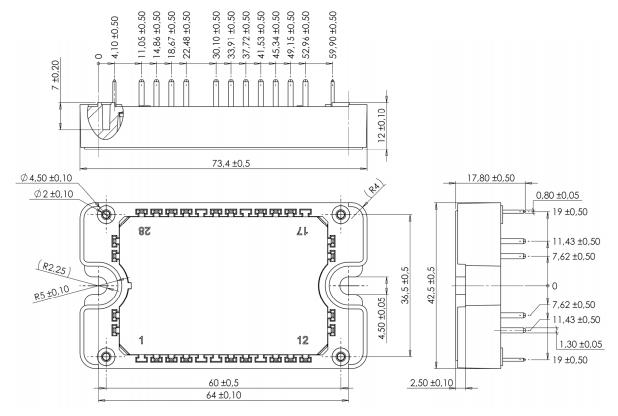
$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz					V	
$T_{\rm J}$	Operating junction temperature range			-40	175		
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C	
T_{STG}	Storage Temperature Range			-40	125		
$T_{\rm C}$	Operating Case Temperature				125		
Torque	Mounting torque	To heatsink	M4	2	3	N.m	
Wt	Package Weight				110	g	

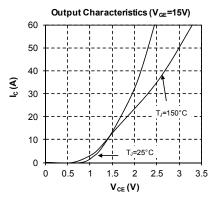
Package outline (dimensions in mm)

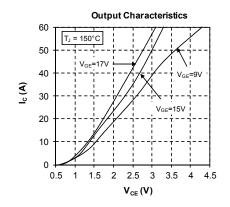


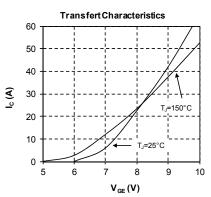
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

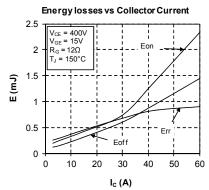


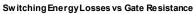
Typical performance curve

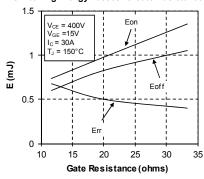


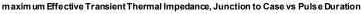


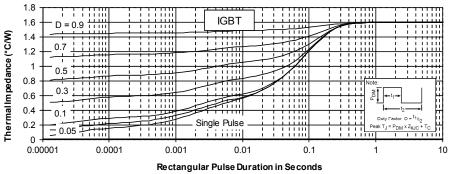




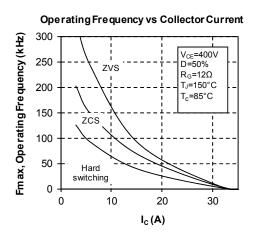


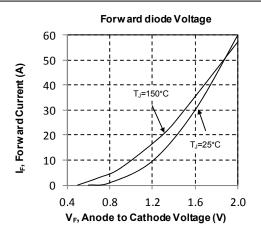




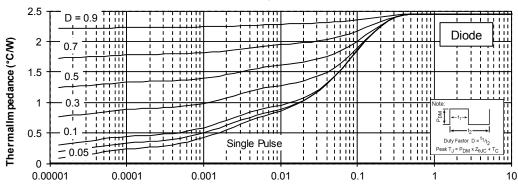








maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



Rectangular Pulse Duration in Seconds

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